

High voltage fast-switching NPN Power Transistor

General features

- NPN Transistor
- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed
- Fully characterized at 125 °C
- In compliance with the 2002/93/EC European Directive

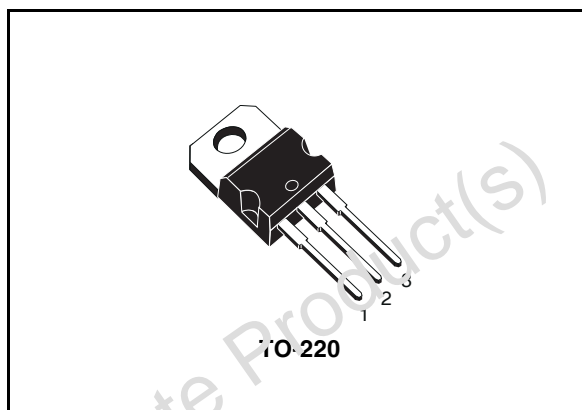
Description

The device is manufactured using high voltage Multi-Epitaxial Planar technology for high switching speeds and medium voltage capability.

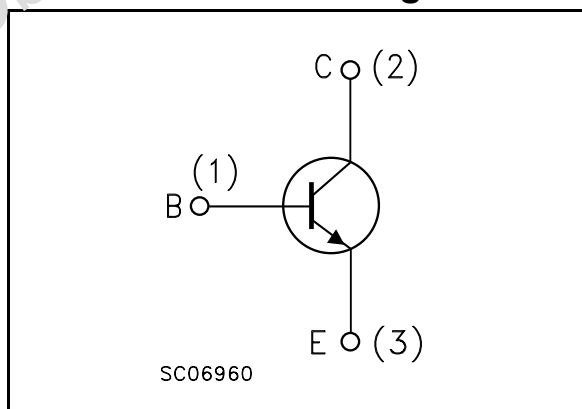
It uses a Cellular Emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.

Applications

- Electronic ballast for fluorescent lighting
- Dedicated for PFC solution in HF ballast half-bridge voltage fed



Internal schematic diagram



Order codes

| Part Number | Marking | Package | Packing |
|-------------|---------|---------|---------|
| BUL705 | BUL705 | TO-220 | Tube |

Contents

| | | |
|----------|---|-----------|
| 1 | Electrical ratings | 3 |
| 2 | Electrical characteristics | 4 |
| 2.1 | Electrical characteristics (curves) | 5 |
| 2.2 | Test circuits | 6 |
| 3 | Package mechanical data | 8 |
| 4 | Revision history | 10 |

1 Electrical ratings

Table 1. Absolute maximum rating

| Symbol | Parameter | Value | Unit |
|-----------|---|------------|------------------|
| V_{CES} | Collector-emitter voltage ($V_{BE} = 0$) | 700 | V |
| V_{CEO} | Collector-emitter voltage ($I_B = 0$) | 400 | V |
| V_{EBO} | Emitter-base voltage ($I_C = 0$) | 10 | V |
| I_C | Collector current | 5 | A |
| I_{CM} | Collector peak current ($t_P < 5\text{ms}$) | 10 | A |
| I_B | Base current | 2 | A |
| I_{BM} | Base peak current ($t_P < 5\text{ms}$) | 4 | A |
| P_{tot} | Total dissipation at $T_C = 25^\circ\text{C}$ | 80 | W |
| T_{stg} | Storage temperature | -65 to 150 | $^\circ\text{C}$ |
| T_J | Max. operating junction temperature | 150 | $^\circ\text{C}$ |

Table 2. Thermal data

| Symbol | Parameter | Value | Unit |
|----------------|----------------------------------|-------|--------------------|
| $R_{thj-case}$ | Thermal resistance junction-case | 1.56 | $^\circ\text{C/W}$ |
| $R_{thj-amb}$ | Thermal resistance junction-amb | 62.5 | $^\circ\text{C/W}$ |

2 Electrical characteristics

($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise specified)

Table 3. Electrical characteristics

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|----------------------------------|---|--|----------|-----------|-------------------|--------------------------------|
| I_{CES} | Collector cut-off current ($V_{\text{BE}} = -1.5\text{V}$) | $V_{\text{CE}} = 700\text{V}$ $V_{\text{CE}} = 700\text{V}$ $T_j = 125^{\circ}\text{C}$ | | | 100 500 | μA μA |
| I_{CEO} | Collector cut-off current ($I_{\text{B}} = 0$) | $V_{\text{CE}} = 400\text{V}$ | | | 250 | μA |
| V_{EBO} | Emitter-base voltage ($I_{\text{C}} = 0$) | $I_{\text{E}} = 10\text{mA}$ | 10 | | | V |
| $V_{\text{CEO(sus)}}^{(1)}$ | Collector-emitter sustaining voltage ($I_{\text{B}} = 0$) | $I_{\text{C}} = 100\text{mA}$ $L = 25\text{mH}$ | 100 | | | V |
| $V_{\text{CE(sat)}}^{(1)}$ | Collector-emitter saturation voltage | $I_{\text{C}} = 2\text{A}$ $I_{\text{B}} = 0.4\text{A}$ $I_{\text{C}} = 3\text{A}$ $I_{\text{B}} = 0.6\text{A}$ $I_{\text{C}} = 4\text{A}$ $I_{\text{B}} = 1\text{A}$ | | | 0.4 0.6 0.8 | V V V |
| $V_{\text{BE(sat)}}^{(1)}$ | Base-emitter saturation voltage | $I_{\text{C}} = 2\text{A}$ $I_{\text{B}} = 0.4\text{A}$ $I_{\text{C}} = 3\text{A}$ $I_{\text{B}} = 0.6\text{A}$ | | | 1.1 1.2 | V V |
| h_{FE} | DC current gain | $I_{\text{C}} = 10\text{mA}$ $V_{\text{CE}} = 5\text{V}$ $I_{\text{C}} = 2\text{A}$ $V_{\text{CE}} = 5\text{V}$ | 10 16 | | 32 | |
| t_{s} | Resistive load Storage time | $V_{\text{CC}} = 250\text{V}$ $I_{\text{C}} = 2\text{A}$ $I_{\text{B1}} = -I_{\text{B2}} = 0.4\text{A}$ (see fig.12) | 2.4 | | 3.5 | μs |
| t_{s} t_{f} | Inductive load Storage time Fall time | $I_{\text{C}} = 2\text{A}$ $I_{\text{B1}} = 0.4\text{A}$ $V_{\text{BE(off)}} = -5\text{V}$ $R_{\text{BB}} = 0\Omega$ $V_{\text{clamp}} = 250\text{V}$ $L = 200\mu\text{H}$ (see fig.13) | | 0.7 50 | 1.4 100 | μs ns |
| t_{s} t_{f} | Inductive load Storage time Fall time | $I_{\text{C}} = 2\text{A}$ $I_{\text{B1}} = 0.4\text{A}$ $V_{\text{BE(off)}} = -5\text{V}$ $R_{\text{BB}} = 0\Omega$ $V_{\text{clamp}} = 250\text{V}$ $L = 200\mu\text{H}$ $T_j = 125^{\circ}\text{C}$ (see fig.13) | | 1 75 | | μs ns |

Note (1) Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

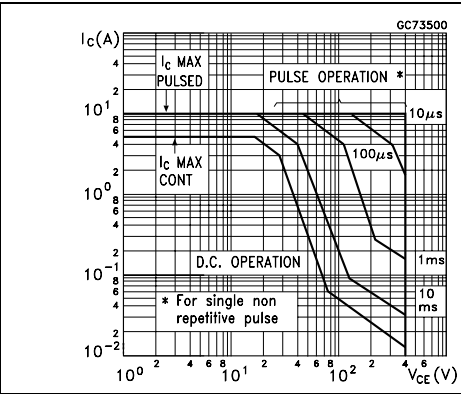


Figure 2. Derating Curve

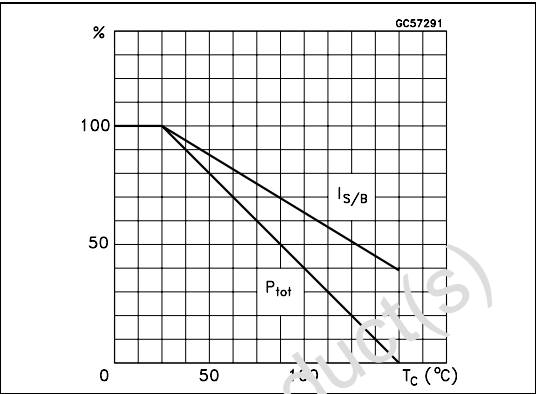


Figure 3. DC current gain

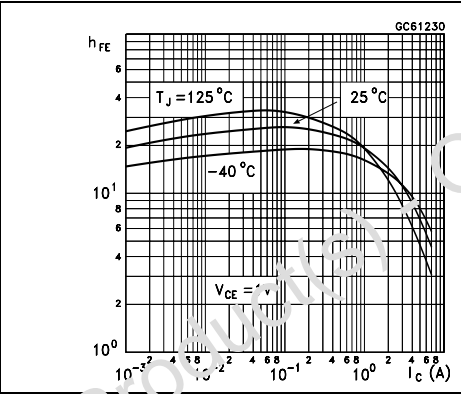


Figure 4. DC current gain

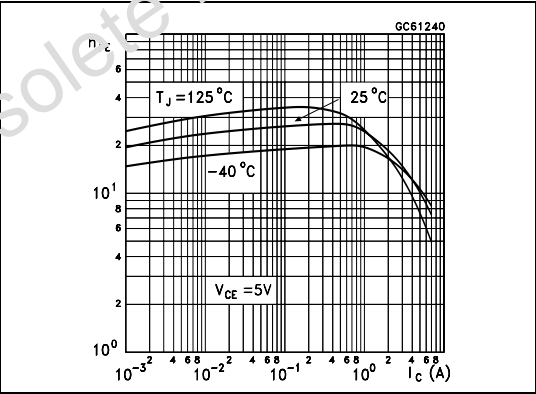


Figure 5. Collector-emitter saturation voltage

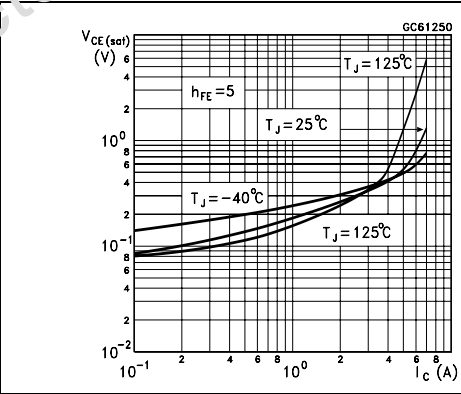


Figure 6. Base-emitter saturation voltage

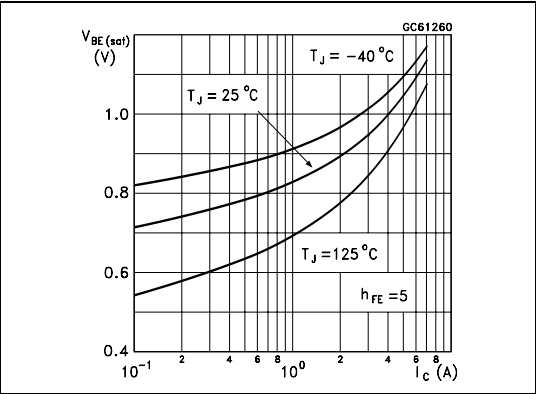


Figure 7. Inductive load fall time

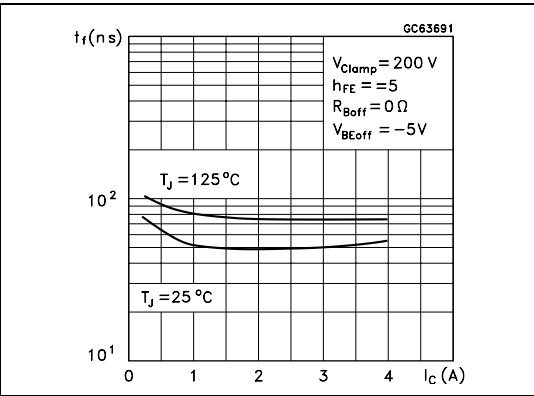


Figure 8. Inductive load storage time

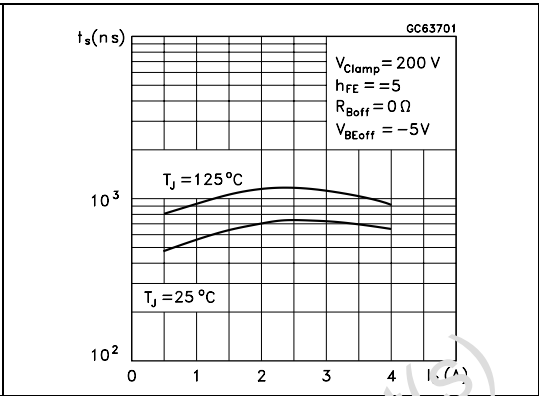
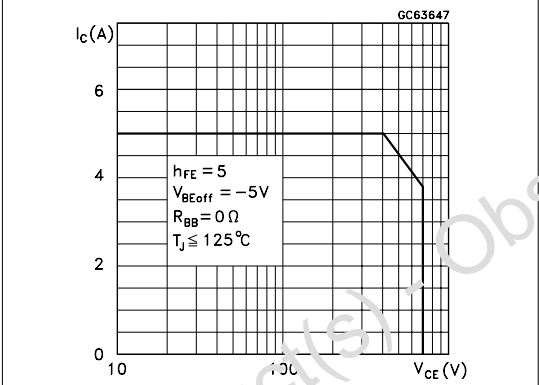
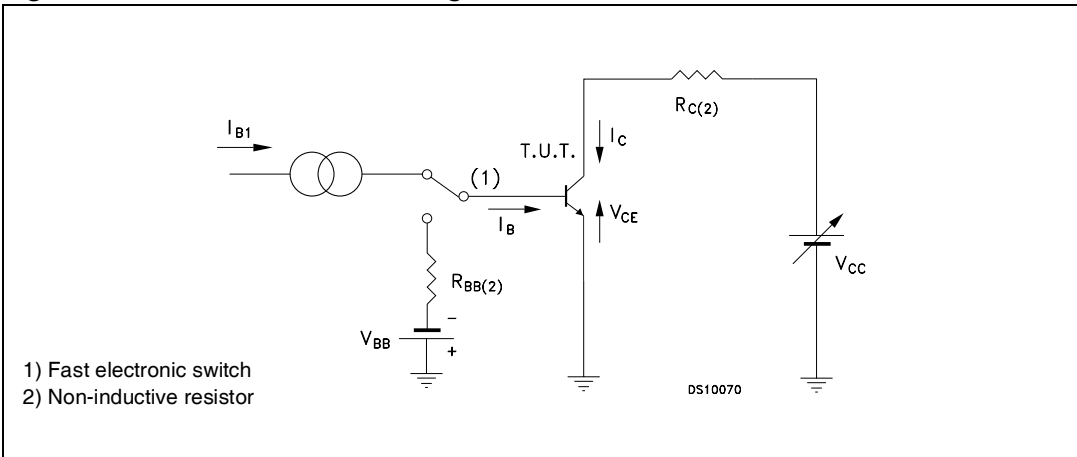


Figure 9. Reverse biased safe operating area



2.2 Test circuits

Figure 10. Resistive load switching test circuit

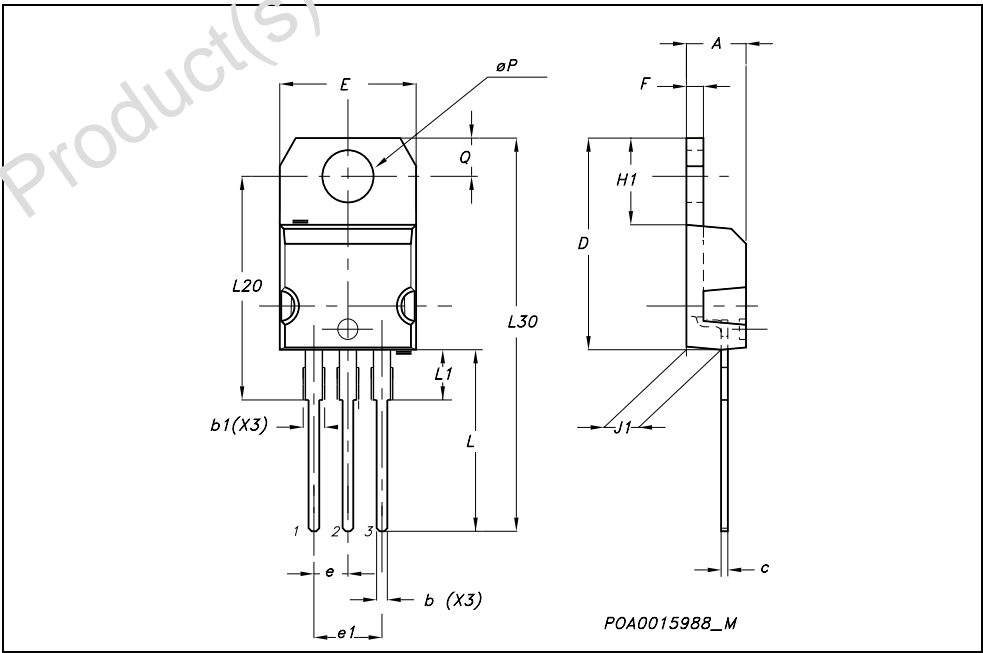


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

Obsolete Product(s) - Obsolete Product(s)

| TO-220 MECHANICAL DATA | | | | | | |
|------------------------|-------|-------|-------|-------|-------|-------|
| DIM. | mm. | | | inch | | |
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | 4.40 | | 4.60 | 0.173 | | 0.181 |
| b | 0.61 | | 0.88 | 0.024 | | 0.034 |
| b1 | 1.15 | | 1.70 | 0.045 | | 0.066 |
| c | 0.49 | | 0.70 | 0.019 | | 0.027 |
| D | 15.25 | | 15.75 | 0.60 | | 0.620 |
| E | 10 | | 10.40 | 0.393 | | 0.409 |
| e | 2.40 | | 2.70 | 0.094 | | 0.106 |
| e1 | 4.95 | | 5.15 | 0.194 | | 0.202 |
| F | 1.23 | | 1.32 | 0.048 | | 0.052 |
| H1 | 6.20 | | 6.60 | 0.244 | | 0.256 |
| J1 | 2.40 | | 2.72 | 0.094 | | 0.107 |
| L | 13 | | 14 | 0.511 | | 0.551 |
| L1 | 3.50 | | 3.93 | 0.137 | | 0.154 |
| L20 | | 16.40 | | | 0.645 | |
| L30 | | 28.90 | | | 1.137 | |
| øP | 3.75 | | 3.93 | 0.147 | | 0.151 |
| Q | 2.65 | | 2.95 | 0.104 | | 0.116 |



4 Revision history

Table 4. Revision history

| Date | Revision | Changes |
|-------------|----------|------------------|
| 22-May-2006 | 1 | Initial release. |

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT DESIGNED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2006 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

